



General Specifications:

Resistive Element:	Thick Film
Substrate:	Aluminum Nitride Ceramic
Terminal Finish:	Tin over Nickel

Features

- DC - 3.0 GHz
- 25 Watts
- Aluminum Nitride (AlN) Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Electrical Specifications:

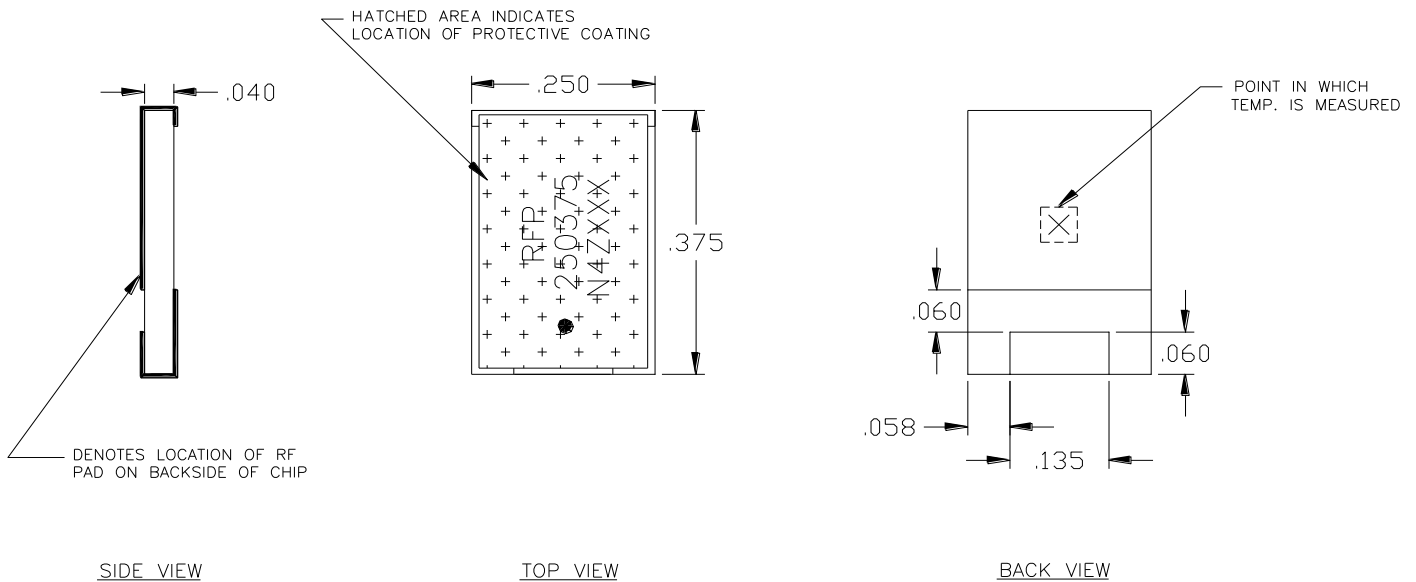
Resistance Range:	50 Ω, ± 2%
Frequency Range:	DC - 3.0 GHz
Power:	25 Watts
VSWR:	1.25:1 DC - 3.0 GHz

Note:

Tolerance is ± 0.010" unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. Operation temperature is -55°C to 125°C (see chart for derating temperatures).

Outline Drawing:

Specifications subject to change without notice.



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